Quad Analog Switch/ Multiplexer/Demultiplexer

High–Performance Silicon–Gate CMOS

MC74VHC4066

The MC74VHC4066 utilizes silicon–gate CMOS technology to achieve fast propagation delays, low ON resistances, and low OFF–channel leakage current. This bilateral switch/multiplexer/demultiplexer controls analog and digital voltages that may vary across the full power–supply range (from V_{CC} to GND).

The VHC4066 is identical in pinout to the metal–gate CMOS MC14066 and the high–speed CMOS HC4066A. Each device has four independent switches. The device has been designed so that the ON resistances (R_{ON}) are much more linear over input voltage than R_{ON} of metal–gate CMOS analog switches.

The ON/OFF control inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs. For analog switches with voltage–level translators, see the VHC4316.

- Fast Switching and Propagation Speeds
- High ON/OFF Output Voltage Ratio
- Low Crosstalk Between Switches
- Diode Protection on All Inputs/Outputs
- Wide Power–Supply Voltage Range (V_{CC} – GND) = 2.0 to 12.0 Volts
- Analog Input Voltage Range (V_{CC} – GND) = 2.0 to 12.0 Volts
- Improved Linearity and Lower ON Resistance over Input Voltage than the MC14016 or MC14066
- Low Noise
- Chip Complexity: 44 FETs or 11 Equivalent Gates

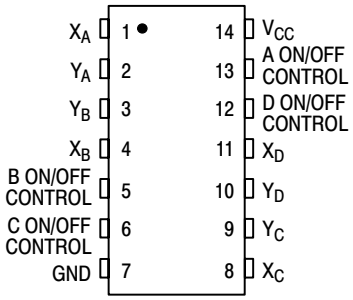
D SUFFIX
14–LEAD SOIC PACKAGE
CASE 751A–03

DT SUFFIX
14–LEAD TSSOP PACKAGE
CASE 948G–01

ORDERING INFORMATION

MC74VHCXXXXD	SOIC
MC74VHCXXXXDT	TSSOP

PIN ASSIGNMENT



FUNCTION TABLE

On/Off Control Input	State of Analog Switch
L	Off
H	On

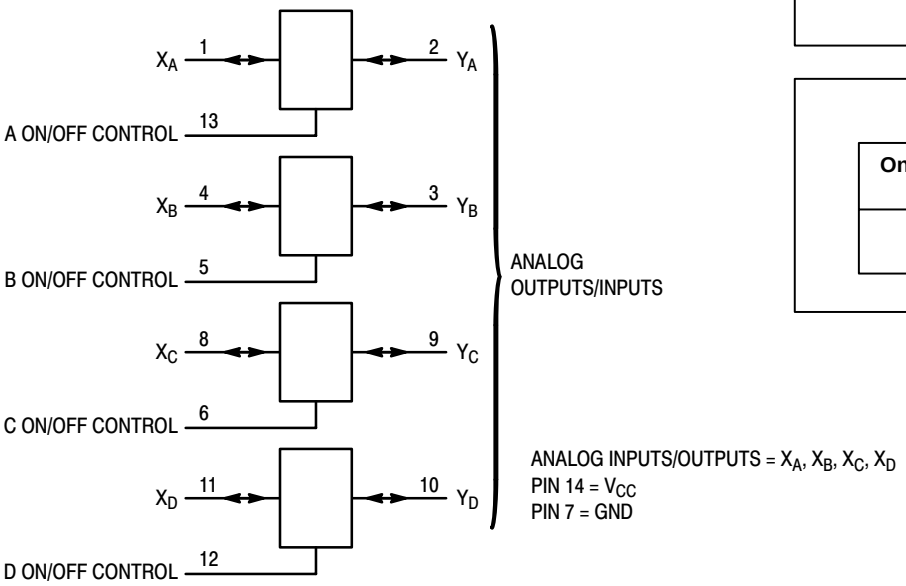


Figure 1. Logic Diagram

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	Positive DC Supply Voltage (Referenced to GND)	– 0.5 to + 14.0	V
V_{IS}	Analog Input Voltage (Referenced to GND)	– 0.5 to V_{CC} + 0.5	V
V_{in}	Digital Input Voltage (Referenced to GND)	– 0.5 to V_{CC} + 0.5	V
I	DC Current Into or Out of Any Pin	± 25	mA
P_D	Power Dissipation in Still Air, SOIC Package†	500	mW
	TSSOP Package†	450	
T_{stg}	Storage Temperature	– 65 to + 150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C

*Maximum Ratings are those values beyond which damage to the device may occur.
Functional operation should be restricted to the Recommended Operating Conditions.
†Derating — SOIC Package: – 7 mW/°C from 65° to 125°C
TSSOP Package: – 6.1 mW/°C from 65° to 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND ≤ (V_{in} or V_{out}) ≤ V_{CC}.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open. I/O pins must be connected to a properly terminated line or bus.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CC}	Positive DC Supply Voltage (Referenced to GND)	2.0	12.0	V
V_{IS}	Analog Input Voltage (Referenced to GND)	GND	V_{CC}	V
V_{in}	Digital Input Voltage (Referenced to GND)	GND	V_{CC}	V
V_{IO}*	Static or Dynamic Voltage Across Switch	—	1.2	V
T_A	Operating Temperature, All Package Types	– 55	+ 125	°C
t_r, t_f	Input Rise and Fall Time, ON/OFF Control Inputs (Figure 14)			ns
	V_{CC} = 2.0 V	0	1000	
	V_{CC} = 3.0 V	0	600	
	V_{CC} = 4.5 V	0	500	
	V_{CC} = 9.0 V	0	400	
	V_{CC} = 12.0 V	0	250	

*For voltage drops across the switch greater than 1.2 V (switch on), excessive V_{CC} current may be drawn; i.e., the current out of the switch may contain both V_{CC} and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded.

DC ELECTRICAL CHARACTERISTIC Digital Section (Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V_{CC} V	Guaranteed Limit			Unit
				– 55 to 25°C	≤ 85°C	≤ 125°C	
V_{IH}	Minimum High–Level Voltage ON/OFF Control Inputs	R_{on} = Per Spec	2.0	1.5	1.5	1.5	V
			3.0	2.1	2.1	2.1	
			4.5	3.15	3.15	3.15	
			9.0	6.3	6.3	6.3	
			12.0	8.4	8.4	8.4	
V_{IL}	Maximum Low–Level Voltage ON/OFF Control Inputs	R_{on} = Per Spec	2.0	0.5	0.5	0.5	V
			3.0	0.9	0.9	0.9	
			4.5	1.35	1.35	1.35	
			9.0	2.7	2.7	2.7	
			12.0	3.6	3.6	3.6	
I_{in}	Maximum Input Leakage Current ON/OFF Control Inputs	V_{in} = V_{CC} or GND	12.0	± 0.1	± 1.0	± 1.0	μA
I_{CC}	Maximum Quiescent Supply Current (per Package)	V_{in} = V_{CC} or GND	6.0	2	20	40	μA
		V_{IO} = 0 V	12.0	4	40	160	

DC ELECTRICAL CHARACTERISTICS Analog Section (Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V_{CC} V	Guaranteed Limit			Unit
				– 55 to 25°C	≤ 85°C	≤ 125°C	
R_{on}	Maximum "ON" Resistance	$V_{in} = V_{IH}$ $V_{IS} = V_{CC}$ to GND $I_S \leq 2.0$ mA (Figures 2 through 7)	2.0† 3.0† 4.5 9.0 12.0	— — 120 70 70	— — 160 85 85	— — 200 100 100	Ω
		$V_{in} = V_{IH}$ $V_{IS} = V_{CC}$ or GND (Endpoints) $I_S \leq 2.0$ mA (Figures 2 through 7)	2.0 3.0 4.5 9.0 12.0	— — 70 50 30	— — 85 60 60	— — 100 80 80	
ΔR_{on}	Maximum Difference in "ON" Resistance Between Any Two Channels in the Same Package	$V_{in} = V_{IH}$ $V_{IS} = 1/2\ (V_{CC} – GND)$ $I_S \leq 2.0$ mA	2.0 4.5 9.0 12.0	— 20 15 15	— 25 20 20	— 30 25 25	Ω
I_{off}	Maximum Off–Channel Leakage Current, Any One Channel	$V_{in} = V_{IL}$ $V_{IO} = V_{CC}$ or GND Switch Off (Figure NO TAG)	12.0	0.1	0.5	1.0	μA
I_{on}	Maximum On–Channel Leakage Current, Any One Channel	$V_{in} = V_{IH}$ $V_{IS} = V_{CC}$ or GND (Figure NO TAG)	12.0	0.1	0.5	1.0	μA

†At supply voltage (V_{CC}) approaching 3 V the analog switch–on resistance becomes extremely non–linear. Therefore, for low–voltage operation, it is recommended that these devices only be used to control digital signals.

AC ELECTRICAL CHARACTERISTICS (C_L = 50 pF, ON/OFF Control Inputs: $t_r = t_f$ = 6 ns)

Symbol	Parameter	V_{CC} V	Guaranteed Limit			Unit
			– 55 to 25°C	≤ 85°C	≤ 125°C	
t_{PLH}, t_{PHL}	Maximum Propagation Delay, Analog Input to Analog Output (Figures 18 and 13)	2.0 3.0 4.5 9.0 12.0	40 30 5 5 5	50 40 7 7 7	60 50 8 8 8	ns
t_{PLZ}, t_{PHZ}	Maximum Propagation Delay, ON/OFF Control to Analog Output (Figures 14 and 15)	2.0 3.0 4.5 9.0 12.0	80 60 20 20 20	90 70 25 25 25	110 80 35 35 35	ns
t_{PZL}, t_{PZH}	Maximum Propagation Delay, ON/OFF Control to Analog Output (Figures 14 and 15)	2.0 3.0 4.5 9.0 12.0	80 45 20 20 20	90 50 25 25 25	100 60 30 30 30	ns
C	Maximum Capacitance — ON/OFF Control Input	—	10	10	10	pF
	Control Input = GND Analog I/O Feedthrough	— —	35 1.0	35 1.0	35 1.0	

		Typical @ 25°C, V_{CC} = 5.0 V	
C_{PD}	Power Dissipation Capacitance (Per Switch) (Figure 17)*	15	pF

* Used to determine the no–load dynamic power consumption: $P_D = C_{PD}\ V_{CC}^2 f + I_{CC}\ V_{CC}$.

ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

Symbol	Parameter	Test Conditions	V_{CC} V	Limit* 25°C 74HC	Unit
BW	Maximum On–Channel Bandwidth or Minimum Frequency Response (Figure NO TAG)	f_{in} = 1 MHz Sine Wave Adjust f_{in} Voltage to Obtain 0 dBm at V_{OS} Increase f_{in} Frequency Until dB Meter Reads – 3 dB R_L = 50 Ω, C_L = 10 pF	4.5 9.0 12.0	150 160 160	MHz
—	Off–Channel Feedthrough Isolation (Figure NO TAG)	f_{in} ≡ Sine Wave Adjust f_{in} Voltage to Obtain 0 dBm at V_{IS} f_{in} = 10 kHz, R_L = 600 Ω, C_L = 50 pF	4.5 9.0 12.0	– 50 – 50 – 50	dB
		f_{in} = 1.0 MHz, R_L = 50 Ω, C_L = 10 pF	4.5 9.0 12.0	– 40 – 40 – 40	
—	Feedthrough Noise, Control to Switch (Figure NO TAG)	V_{in} ≤ 1 MHz Square Wave (t_r = t_f = 6 ns) Adjust R_L at Setup so that I_S = 0 A R_L = 600 Ω, C_L = 50 pF	4.5 9.0 12.0	60 130 200	mV_{PP}
		R_L = 10 kΩ, C_L = 10 pF	4.5 9.0 12.0	30 65 100	
—	Crosstalk Between Any Two Switches (Figure 16)	f_{in} ≡ Sine Wave Adjust f_{in} Voltage to Obtain 0 dBm at V_{IS} f_{in} = 10 kHz, R_L = 600 Ω, C_L = 50 pF	4.5 9.0 12.0	– 70 – 70 – 70	dB
		f_{in} = 1.0 MHz, R_L = 50 Ω, C_L = 10 pF	4.5 9.0 12.0	– 80 – 80 – 80	
THD	Total Harmonic Distortion (Figure 20)	f_{in} = 1 kHz, R_L = 10 kΩ, C_L = 50 pF THD = $THD_{Measured}$ – THD_{Source} V_{IS} = 4.0 V_{PP} sine wave V_{IS} = 8.0 V_{PP} sine wave V_{IS} = 11.0 V_{PP} sine wave	 4.5 9.0 12.0	 0.10 0.06 0.04	%

*Guaranteed limits not tested. Determined by design and verified by qualification.

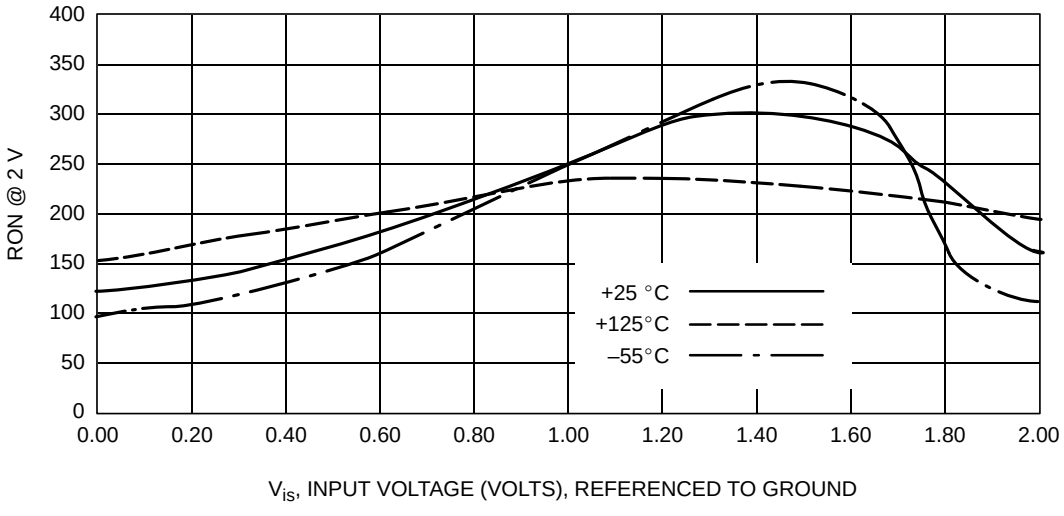


Figure 2. Typical On Resistance, V_{CC} = 2.0 V

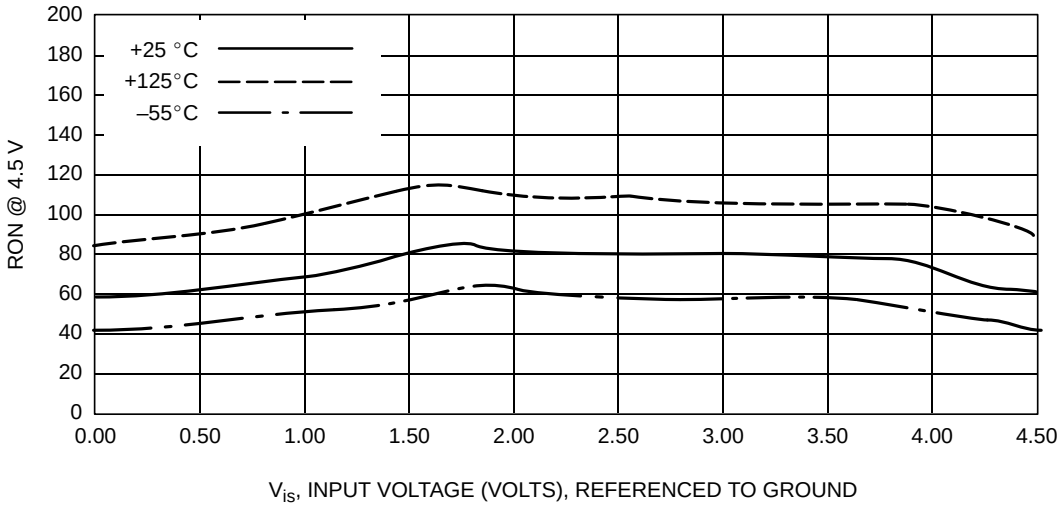


Figure 3. Typical On Resistance, V_{CC} = 4.5 V

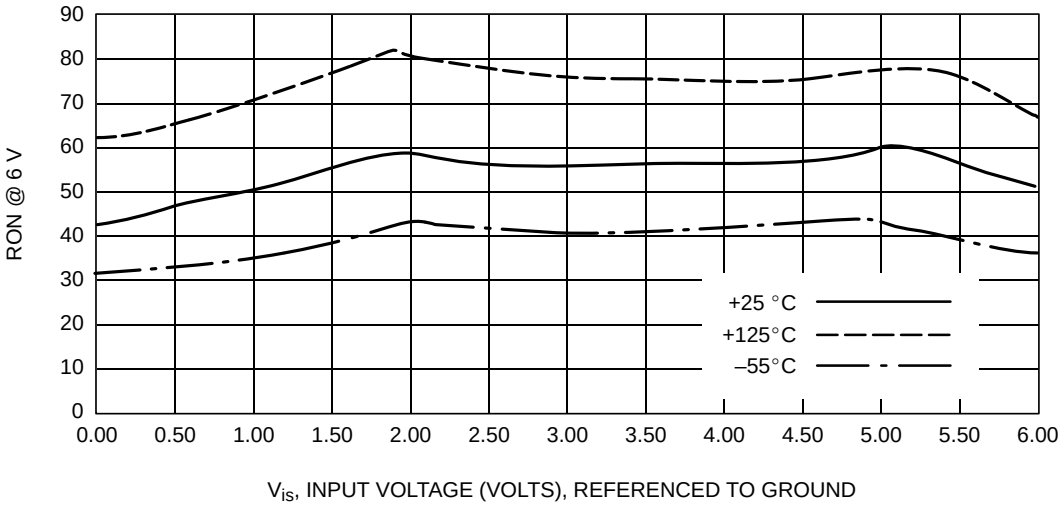


Figure 4. Typical On Resistance, V_{CC} = 6.0 V

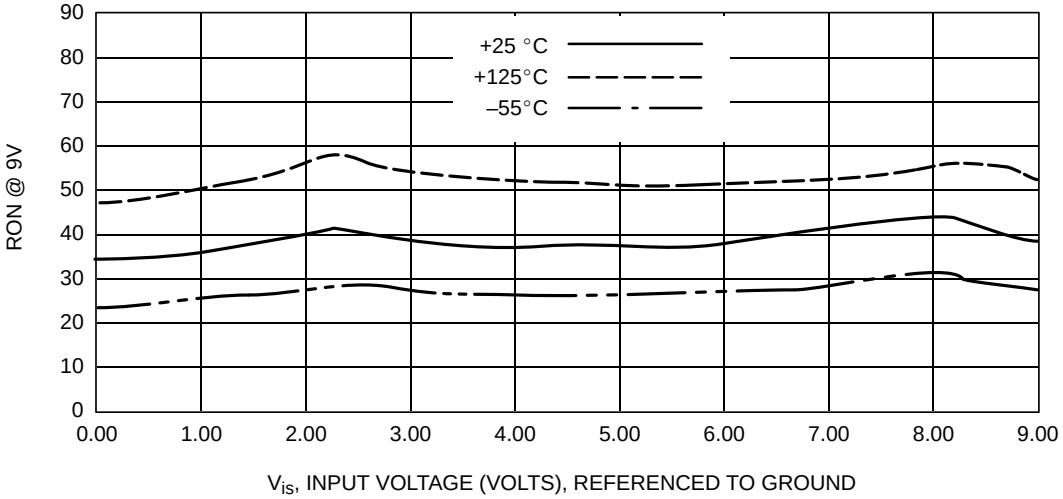


Figure 5. Typical On Resistance, V_{CC} = 9.0 V

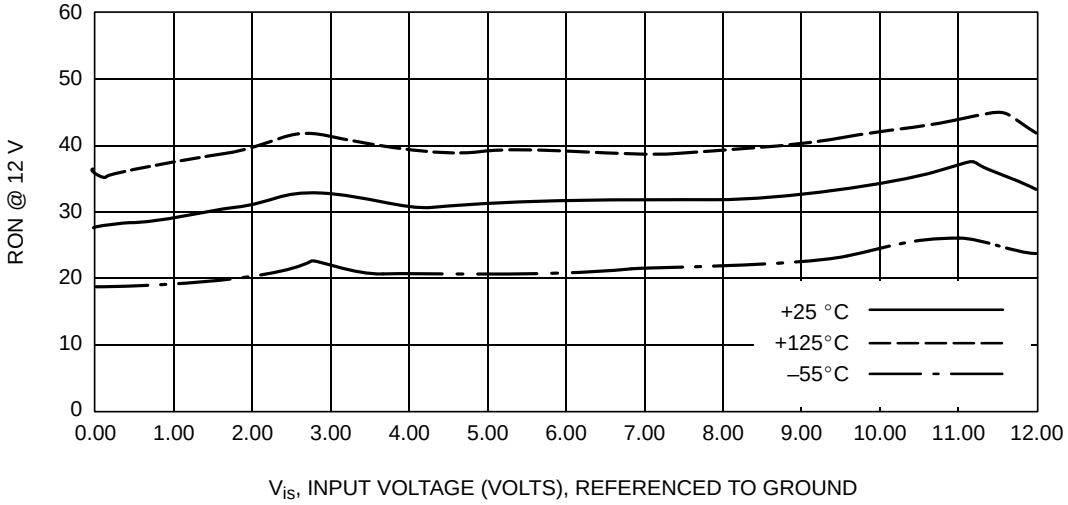


Figure 6. Typical On Resistance, V_{CC} = 12 V

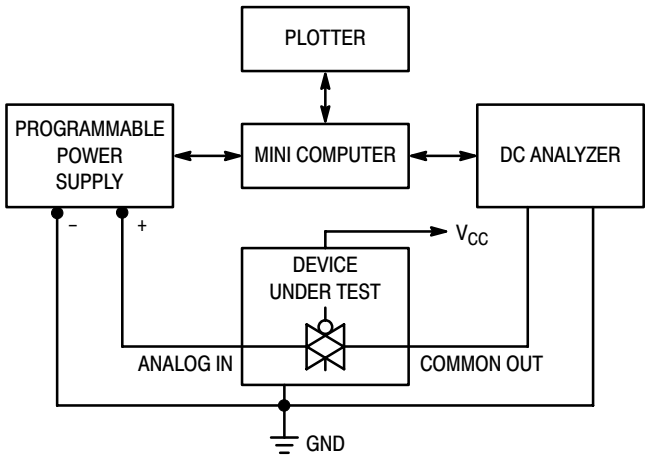


Figure 7. On Resistance Test Set–Up

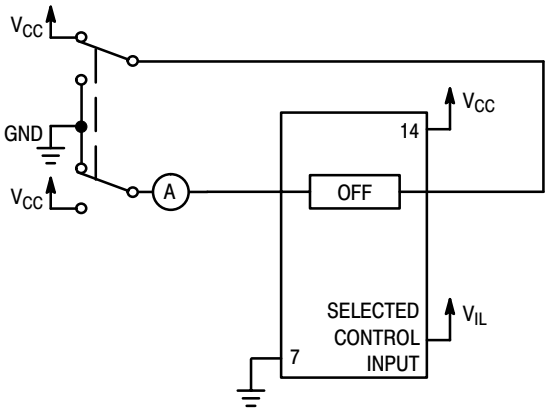


Figure 8. Maximum Off Channel Leakage Current, Any One Channel, Test Set–Up

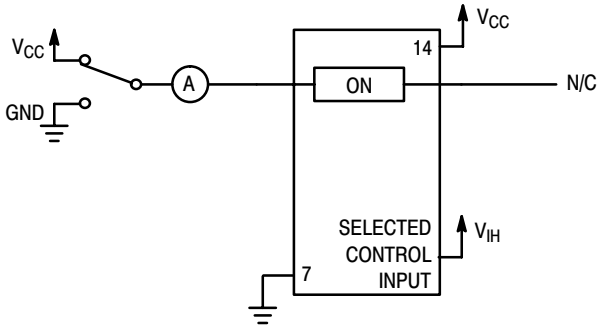
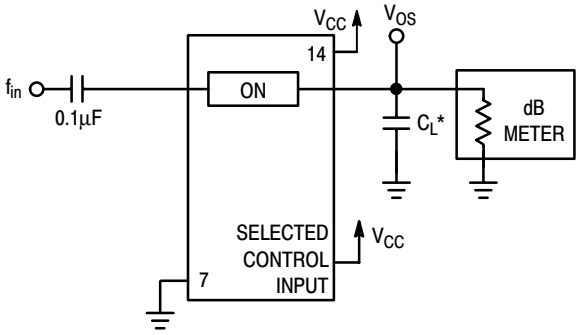
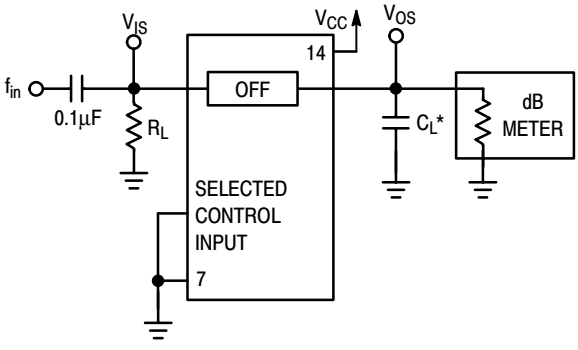


Figure 9. Maximum On Channel Leakage Current, Test Set–Up



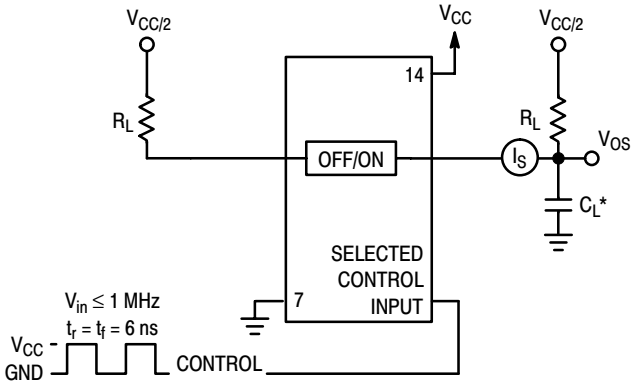
*Includes all probe and jig capacitance.

Figure 10. Maximum On–Channel Bandwidth Test Set–Up



*Includes all probe and jig capacitance.

Figure 11. Off–Channel Feedthrough Isolation, Test Set–Up



*Includes all probe and jig capacitance.

Figure 12. Feedthrough Noise, ON/OFF Control to Analog Out, Test Set–Up

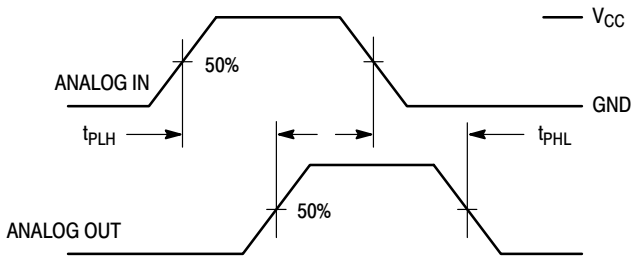
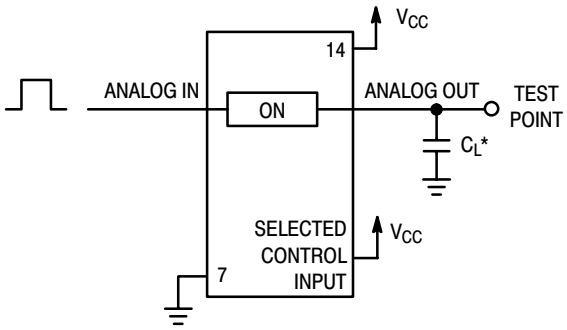


Figure 18. Propagation Delays, Analog In to Analog Out



*Includes all probe and jig capacitance.

Figure 13. Propagation Delay Test Set–Up

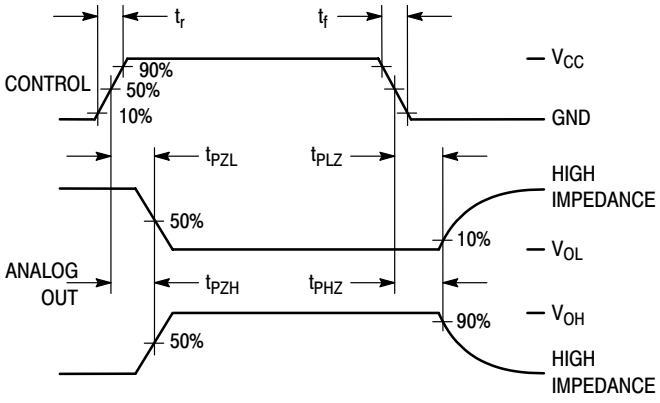
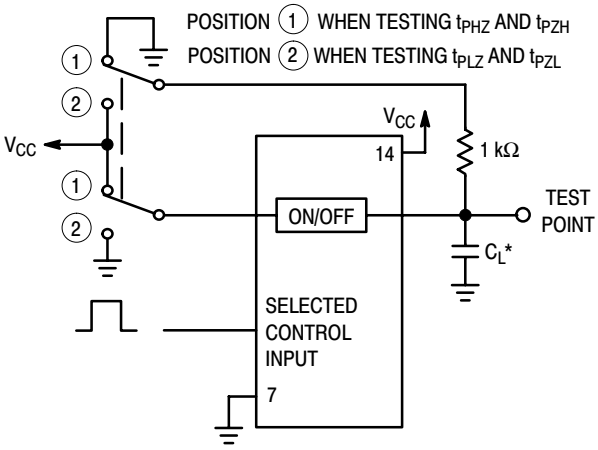
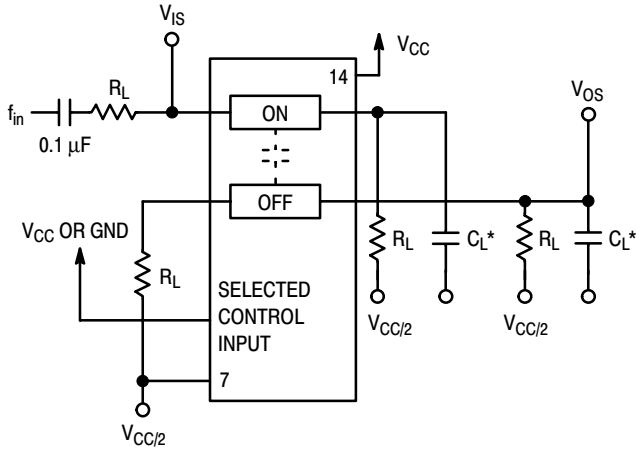


Figure 14. Propagation Delay, ON/OFF Control to Analog Out



*Includes all probe and jig capacitance.

Figure 15. Propagation Delay Test Set–Up



*Includes all probe and jig capacitance.

Figure 16. Crosstalk Between Any Two Switches, Test Set–Up

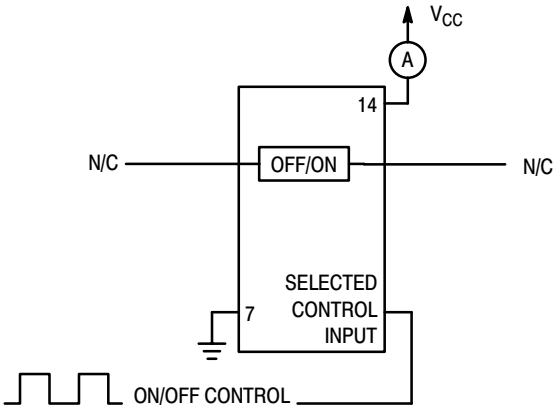
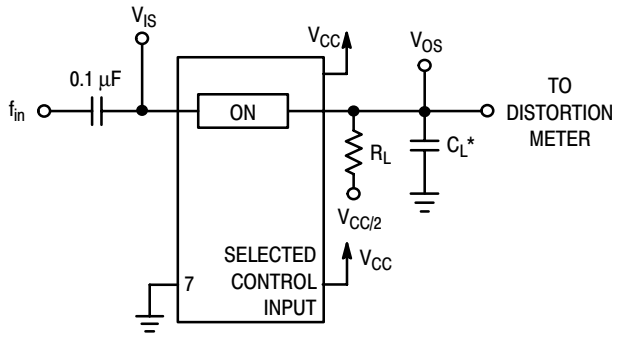


Figure 17. Power Dissipation Capacitance Test Set–Up



*Includes all probe and jig capacitance.

Figure 20. Total Harmonic Distortion, Test Set–Up

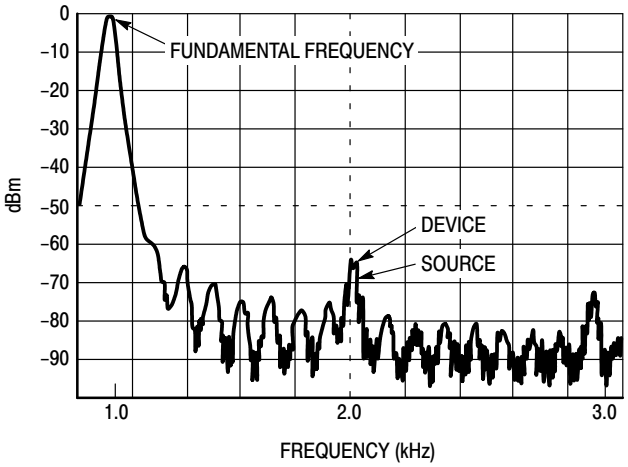


Figure 19. Plot, Harmonic Distortion

APPLICATION INFORMATION

The ON/OFF Control pins should be at V_{CC} or GND logic levels, V_{CC} being recognized as logic high and GND being recognized as a logic low. Unused analog inputs/outputs may be left floating (not connected). However, it is advisable to tie unused analog inputs and outputs to V_{CC} or GND through a low value resistor. This minimizes crosstalk and feedthrough noise that may be picked–up by the unused I/O pins.

The maximum analog voltage swings are determined by the supply voltages V_{CC} and GND. The positive peak analog voltage should not exceed V_{CC}. Similarly, the negative peak analog voltage should not go below GND. In the example below, the difference between V_{CC} and GND is twelve volts. Therefore, using the configuration in Figure 21, a maximum analog signal of twelve volts peak–to–peak can be controlled.

When voltage transients above V_{CC} and/or below GND are anticipated on the analog channels, external diodes (Dx) are recommended as shown in Figure 22. These diodes should be small signal, fast turn–on types able to absorb the maximum anticipated current surges during clipping. An alternate method would be to replace the Dx diodes with Mosorbs (high current surge protectors). Mosorbs are fast turn–on devices ideally suited for precise DC protection with no inherent wear out mechanism.

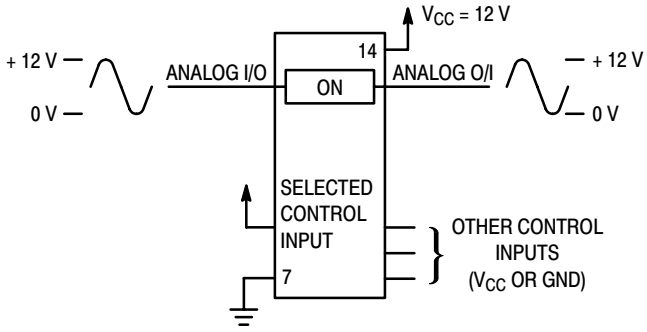


Figure 21. 12 V Application

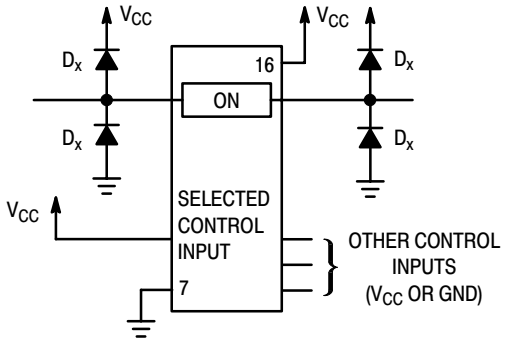
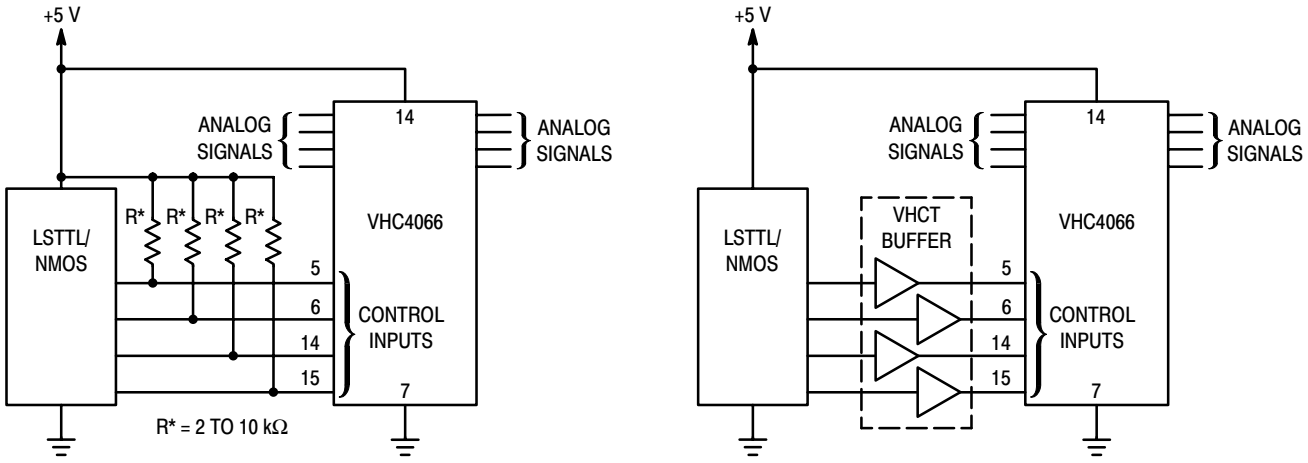


Figure 22. Transient Suppressor Application



a. Using Pull-Up Resistors **b. Using HCT Buffer**

Figure 23. LSTTL/NMOS to HCMOS Interface

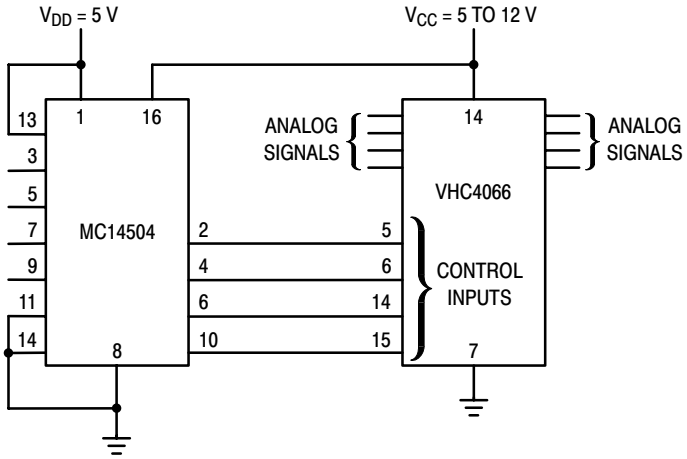


Figure 24. TTL/NMOS–to–CMOS Level Converter Analog Signal Peak–to–Peak Greater than 5 V (Also see VHC4316)

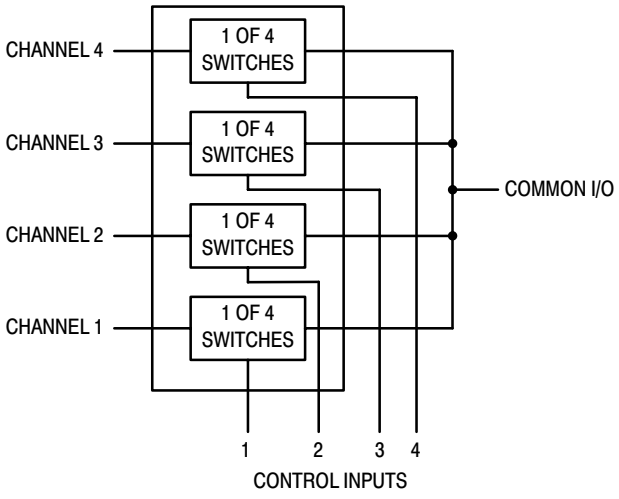


Figure 25. 4–Input Multiplexer

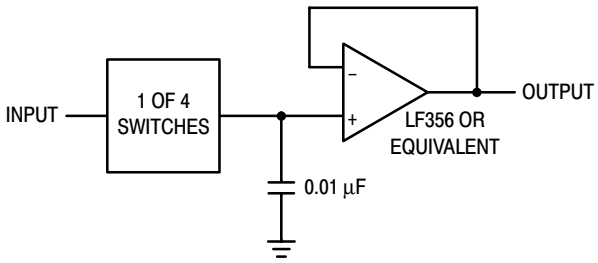
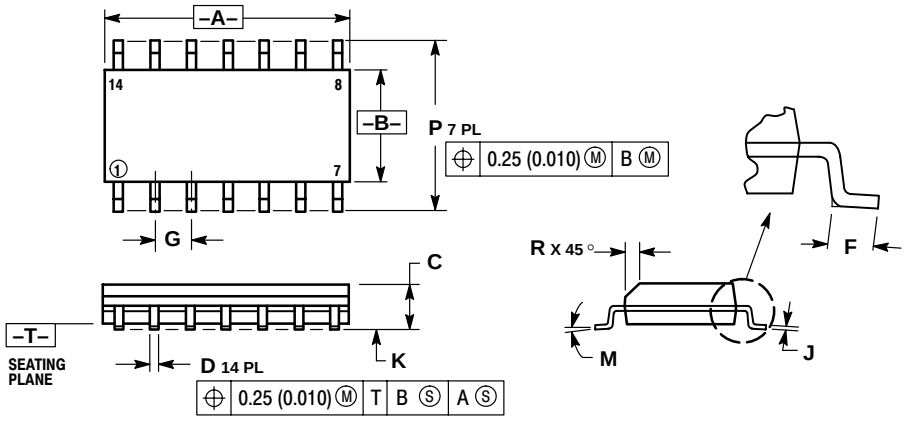


Figure 26. Sample/Hold Amplifier

OUTLINE DIMENSIONS

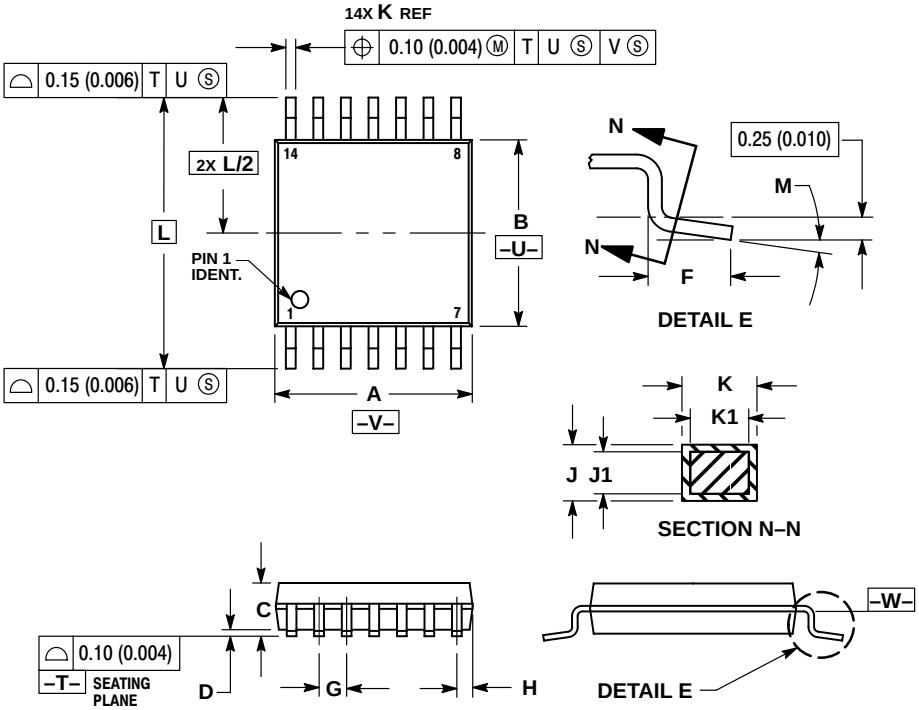
D SUFFIX
SOIC–14
CASE 751A–03
ISSUE F



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	8.55	8.75	0.337	0.344
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0 °	7 °	0 °	7 °
P	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

DT SUFFIX
TSSOP
CASE 948G–01
ISSUE O



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE –W–.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0 °	8 °	0 °	8 °

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